



光接收電晶體

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- Applications**
- VCRs, cassette tape recorders
 - Floppy disk drives
 - Optoelectronic switches
 - Automatic stroboscopes

SHARP

Part No.	Product No.	製造廠商	說明	Vceo	△θ(deg)	λP(nm)	Package
34464	PT480F	SHARP	Narrow Acceptance Phototransistor	35V	+13	800nm	Epoxy resin



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SHARP

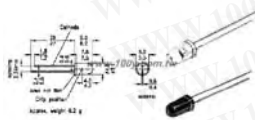
Part No.	Product No.	製造廠商	說明	Vceo	Light Cur. (mA)	△θ(deg)	λP(nm)	Package	重量
34468	PT481F	SHARP	Narrow Acceptance High Sensitivity Phototransistor	35V	10mA	+13	860nm	Epoxy resin	0.2g



- Applications**
- Optoelectronic switches, optoelectronic counters
 - Smoke detectors
 - Infrared applied systems

SHARP

Part No.	Product No.	製造廠商	說明	Vceo	△θ(deg)	λP(nm)	Package	重量
34469	PT510	SHARP	TO-18 Type Narrow Acceptance Phototransistor	35V	+6	800nm	TO-18	1.7g



SIEMENS

Part No.	Product No.	製造廠商	說明	Vceo	△θ(deg)	λP(nm)	Package
35030	SFH309FA-4	SIEMENS	Silicon NPN Phototransistor	35V	+12	900nm	3mm
35087	SFH313FA-2	SIEMENS	Silicon NPN Phototransistor	70V	+10	880nm	5mm



The ST-1CL3H is a high-sensitivity NPN silicon phototransistor mounted in Φ3 ceramic package, The small size and low-cost make it highly suitable for use in detector array and for both private and industrial uses

Part No.	Product No.	製造廠商	說明	Vceo	Light Cur. (mA)	△θ(deg)	λP(nm)	Package	重量
60471	ST-1CL3H	KODENSHI	Phototransistor	20V	1.5mA	±50	800	φ3ceramic package	0.1g



The ST-1KLA are high-sensitivity NPN silicon phototransistors mounted on durable, hermetically sealed TO-18 metal cans, providing years of reliable performance even under demanding conditions such as use outdoors

Part No.	Product No.	製造廠商	說明	Vceo	Light Cur. (mA)	△θ(deg)	λP(nm)	Package
18160	ST-1KLA	KODENSHI	Photo Transistor	40	6	±15	880	TO-18



The ST-1MLBR2 are high-sensitivity NPN silicon photo-encapsulation and with visible light cut-off filters, so that the phototransistors are sensitive only to infrared rays

Part No.	Product No.	製造廠商	說明	Vceo	Light Cur. (mA)	△θ(deg)	λP(nm)	Package
18159	ST-1MLBR2	KODENSHI	Photo Transistor	40	1.2	±70	940	TO-18



- FEATURES**
- Wide angular response
 - Relatively low-cost against metal can package
 - Low profile package

- APPLICATIONS**
- Optical counters
 - Infrared sensors
 - Camera stroboscopes

Part No.	Product No.	製造廠商	說明	Vceo	Light Cur. (mA)	△θ(deg)	λP(nm)	Package	重量
47571	ST-1MLB	KODENSHI	KODENSHI 光接收電晶體	40V	30mA	±70	880 nm	TO-18	0.2g



Part No.	Product No.	製造廠商	說明	Vceo	Light Cur. (mA)	△θ(deg)	λP(nm)	Package
43451	ST-2L2B	KODENSHI	光接收電晶體	30V	20mA	±20	940nm	TO-18

